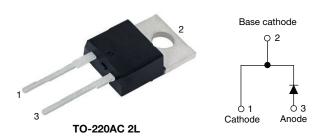


ROHS

HALOGEN FREE

Hyperfast Rectifier, 8 A FRED Pt® G5



LINKS TO ADDITIONAL RESOURCES





PRIMARY CHARACTERISTICS					
I _{F(AV)}	8 A				
V _R	1200 V				
V _F at I _F at 125 °C	1.8 V				
t _{rr}	33 ns				
T _J max.	175 °C				
Package	TO-220AC 2L				
Circuit configuration	Single				

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating **Terminals:** matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 122 °C, D = 0.50	8				
Repetitive peak forward current	I _{FRM}	T _C = 122 °C, D = 0.50, f = 20 kHz	16	Α			
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	65				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	1200	-	-			
Forward voltage	V _F	I _F = 8 A	-	1.9	2.5	V		
		I _F = 8 A, T _J = 125 °C	-	1.8	-			
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	50			
neverse leakage current		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$		500	μA			
Junction capacitance	C _T	V _R = 200 V	-	5	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	=.	nH		





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
		T _J = 25 °C	1 A, 30 V, 100 A/μs	-	33	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	100	-	ns	
		T _J = 125 °C		-	165	-		
Dook recovery ourrent	1	T _J = 25 °C	$I_F = 6 A$	-	8.0	-	А	
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 400 A/μs V _R = 400 V	-	10	-		
Doverso vecessom charge	Q _{rr}	T _J = 25 °C		-	300	-	nC	
Reverse recovery charge		T _J = 125 °C		-	700	-		
Poverse receivery time		T _J = 25 °C		-	60	-	ns	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	80	-		
Dools recovery oursent		T _J = 25 °C	$I_F = 8 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 800 \text{ V}$	-	16	-	A	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	26	-		
Doverso vecessom seberge		T _J = 25 °C		-	570	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1350	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	2.3	°C/W		
Weight			-	2	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style TO-220AC 2L	E5TH0812TH					

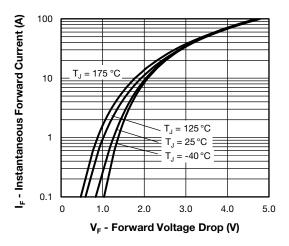


Fig. 1 - Forward Voltage Drop Characteristics

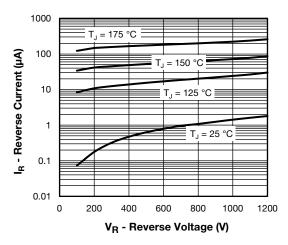


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

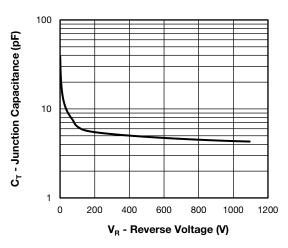


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

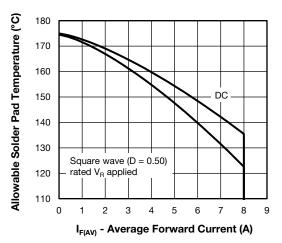


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

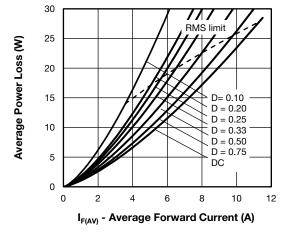


Fig. 5 - Forward Power Loss Characteristics

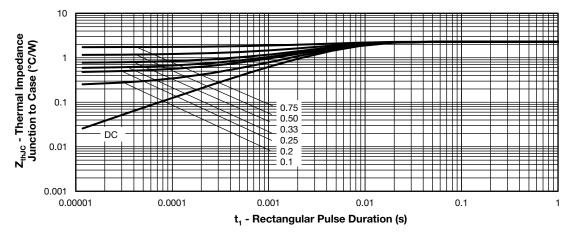


Fig. 6 - Transient Thermal Impedance, Junction to Case

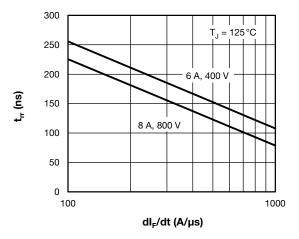


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

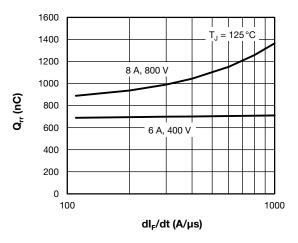


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

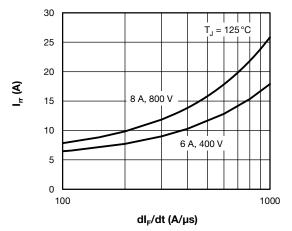


Fig. 9 - Typical Reverse Recovery Current vs. dI_F/dt

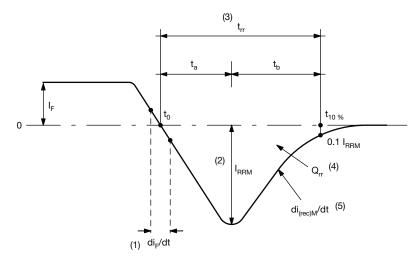


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

(1) di_F/dt - rate of change of current through zero crossing

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- (2) I_{RRM} peak reverse recovery current
 (3) t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
 (4) Q_{rr} area under curve defined by t₀ and t_{10 %}

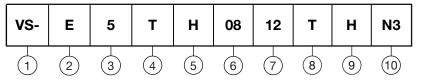
$$Q_{rr} = \int_{t_0}^{\tau_{10} \%} I(t) dt$$

(5) di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- E = single diode

3 - 5 = FRED generation 5

4 - Package:

T = TO-220AC 2L

5 - H = hyperfast recovery

6 - Current rating (08 = 8 A)

7 - Voltage rating (12 = 1200 V)

8 - T = true 2 pin TO-220AC

9 - H = AEC-Q101 qualified

10 - Environmental digit:

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

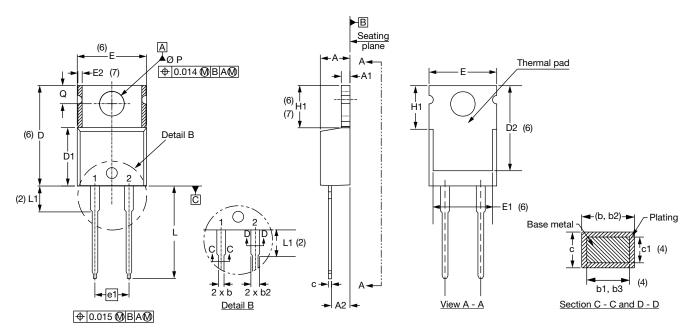
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5TH0812THN3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96069				
Part marking information	www.vishay.com/doc?95391				



TO-220AC 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOIES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e1	4.88	5.28	0.192	0.208	
H1	5.84	6.86	0.230	0.270	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"



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